

L Number	Hits	Search Text	DB	Time stamp
31	102	310/\$.ccls. and ((strain\$7 induc\$7) near12 silicon\$10)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/05/31 11:06
32	51	(310/\$.ccls. and ((strain\$7 induc\$7) near12 silicon\$10)) and piezo\$12	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/05/31 10:35
33	67	333/\$.ccls. and ((strain\$7 induc\$7) near12 silicon\$10)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/05/31 11:11
34	52	29/\$.ccls. and ((strain\$7 induc\$7) near12 silicon\$10) and piezo\$12	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/05/31 11:44
35	246	((induc\$7) near12 silicon\$10) and piezo\$12	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/05/31 12:53
36	19	electrostrict\$5 near12 silicon\$10 and piezo\$12	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/05/31 11:57
-	3	310/328 and porous near silicon	USPAT	2002/05/30 17:24
-	6	310/\$.ccls. and porous near silicon	USPAT; EPO; JPO; DERWENT	2001/07/03 17:16
-	0	"US 6160331 A".DID. and electrode	USPAT; EPO; JPO; DERWENT	2001/07/03 13:52
-	2774	porous near silicon	USPAT; EPO; JPO; DERWENT	2001/07/03 13:53
-	55	(porous near silicon) and piezo\$ and electrode	USPAT; EPO; JPO; DERWENT	2001/07/03 15:36
-	0	(porous near silicon) and piezo near optic and electrode	USPAT; EPO; JPO; DERWENT	2001/07/03 13:58
-	0	(porous near silicon) and piezooptic	USPAT; EPO; JPO; DERWENT	2001/07/03 15:53
-	0	310/\$.ccls. and piezooptic and electrode	USPAT; EPO; JPO; DERWENT	2001/07/03 19:00
-	3	piezooptic and electrode	USPAT; EPO; JPO; DERWENT	2001/07/03 13:59
-	4	((porous near silicon) and piezo\$ and electrode) and strain near induce\$	USPAT; EPO; JPO; DERWENT	2001/07/03 15:41
-	47	((porous near silicon) and piezo\$ and electrode) and crystal	USPAT; EPO; JPO; DERWENT	2001/11/20 10:48
-	3	piezooptic and electrode	USPAT; EPO; JPO; DERWENT	2001/07/03 16:00
-	2	(piezooptic and electrode) and light	USPAT; EPO; JPO; DERWENT	2001/07/03 16:01
-	2	(piezooptic and electrode) and strain	USPAT; EPO; JPO; DERWENT	2001/07/03 16:01

-	1000	310/330 or 310/331 and strain near induced and electrode	USPAT	2001/07/03 16:41
-	30	(310/330 or 310/331) and strain near induced and electrode	USPAT	2001/07/03 17:10
-	2	((310/330 or 310/331) and strain near induced and electrode) and porous	USPAT	2001/07/03 17:11
-	1	310/\$.ccls. and light near induce\$ and piezo\$	USPAT; EPO; JPO; DERWENT	2001/07/03 17:26
-	48	light near induce\$ and piezo\$ and electrode	USPAT; EPO; JPO; DERWENT	2001/07/03 18:59
-	3	(light near induce\$ and piezo\$ and electrode) and strain\$ near induce\$	USPAT; EPO; JPO; DERWENT	2001/07/03 18:38
-	3	(light near induce\$ and piezo\$ and electrode) and crystal and porous	USPAT; EPO; JPO; DERWENT	2001/07/03 18:39
-	6	(light near induce\$ and piezo\$ and electrode) and porous	USPAT; EPO; JPO; DERWENT	2001/07/03 18:39
-	1	310/\$.ccls. and piezooptic	USPAT; EPO; JPO; DERWENT	2001/11/19 12:27
-	17	((porous near silicon) and piezo\$ and electrode) and crystal) and strain	USPAT; EPO; JPO; DERWENT	2001/07/03 19:40
-	20	310/\$.ccls. and piezo\$ near optic\$	USPAT; EPO; JPO; DERWENT	2001/11/20 09:09
-	2	333/\$.ccls. and piezo\$ near optic\$	USPAT; EPO; JPO; DERWENT	2001/11/19 12:32
-	2	29/\$.ccls. and piezo\$ near optic\$	USPAT; EPO; JPO; DERWENT	2001/11/19 12:32
-	14	("1930905" "2614163" "2750796" "2984111" "3093760" "3192763" "3239789" "3350942" "3386282" "3470400" "3479536" "3879992" "3967490" "4155257").PN.	USPAT	2001/11/19 13:53
-	0	333/\$.ccls. and piezo\$ and porous\$ near (element\$ or device or piece\$)	USPAT; EPO; JPO; DERWENT	2001/11/20 09:23
-	4	310/\$.ccls. and piezo\$ and porous\$ near (element\$ or device or piece\$)	USPAT; EPO; JPO; DERWENT	2001/11/20 10:42
-	1	("6021675").PN.	USPAT	2001/11/20 10:42
-	36	29/\$.ccls. and porous\$ same (element\$ or device or part\$ or piece\$) and piezo\$	USPAT; EPO; JPO; DERWENT	2001/11/20 11:48
-	0	29/\$.ccls. and induc\$ same strain\$ same element\$ and porous\$ and piezo\$	USPAT; EPO; JPO; DERWENT	2001/11/20 12:14
-	3	310/\$.ccls. and induc\$ same strain\$ same element\$ and porous\$ and piezo\$	USPAT; EPO; JPO; DERWENT	2001/11/20 12:01
-	2	29/\$.ccls. and induc\$ same strain\$ same element\$ and porous\$	USPAT; EPO; JPO; DERWENT	2001/11/20 12:22
-	0	333/\$.ccls. and induc\$ same strain\$ same element\$ and porous\$	USPAT; EPO; JPO; DERWENT	2001/11/20 12:28
-	3	310/\$.ccls. and induc\$ same strain\$ same element\$ and porous\$	USPAT; EPO; JPO; DERWENT	2001/11/20 13:10
-	7	induc\$ same strain\$ same element\$ and porous\$ and piezo\$	USPAT; EPO; JPO; DERWENT	2001/11/20 12:44
-	41	(radio and light and micro) same wave\$ and (light same source)	USPAT; EPO; JPO; DERWENT	2001/11/20 12:48

-	3	(radio near wave and light near wave and micro near wave)	USPAT; EPO; JPO; DERWENT	2001/11/20 12:49
-	4	(radio near wave\$ and light near wave\$ and micro near wave\$)	USPAT; EPO; JPO; DERWENT	2001/11/20 12:51
-	681	reflect\$ and electrode\$ and micro\$ same wave\$	USPAT; EPO; JPO; DERWENT	2001/11/20 12:59
-	108	(reflect\$ and electrode\$ and micro\$ same wave\$) and reflector\$	USPAT; EPO; JPO; DERWENT	2001/11/20 13:01
-	6	((reflect\$ and electrode\$ and micro\$ same wave\$) and reflector\$) and porous\$	USPAT; EPO; JPO; DERWENT	2001/11/20 13:01
-	1	310/\$.ccls. and (reflector\$ or reflect\$ near (surface\$ or layer\$)) same porous\$	USPAT; EPO; JPO; DERWENT	2001/11/20 13:21
-	3	333/\$.ccls. and (reflector\$ or reflect\$ near (surface\$ or layer\$)) same porous\$	USPAT; EPO; JPO; DERWENT	2001/11/20 13:44
-	0	437/\$.ccls. and (reflector\$ or reflect\$ near (surface\$ or layer\$)) same porous\$	USPAT; EPO; JPO; DERWENT	2001/11/20 13:53
-	4	29/\$.ccls. and (reflector\$ or reflect\$ near (surface\$ or layer\$)) same porous\$	USPAT; EPO; JPO; DERWENT	2001/11/20 13:59
-	14	73/\$.ccls. and (reflector\$ or reflect\$ near (surface\$ or layer\$)) same porous\$	USPAT; EPO; JPO; DERWENT	2001/11/20 15:07
-	0	(437/228).CCLS.	USPAT	2001/11/20 15:07
-	1	("5814920").PN.	USPAT	2001/11/20 16:01
-	6	((("6021675") or ("5569626") or ("4882499") or ("5378551") or ("5852337") or ("5814920"))).PN.	USPAT	2001/11/20 16:02
-	1	("5349857").PN.	USPAT	2001/11/21 13:15
-	3	"5021929"	USPAT	2001/11/21 13:15
-	2	((("6168948") or ("5801069"))).PN.	USPAT	2002/02/26 18:51
-	1	((("6168948") or ("5801069"))).PN.) and (induce\$ or strain\$)	USPAT	2002/02/26 18:52
-	5	((("6048622") or ("5852337") or ("5814920") or ("3805601") or ("6043587"))).PN.	USPAT	2002/02/26 18:57
-	1	("5665250").PN.	USPAT	2002/02/26 18:59
-	7	((("6177291") or ("6172902") or ("6168948") or ("6021675") or ("5801069") or ("5978524") or ("5665250"))).PN.	USPAT	2002/02/26 19:28
-	2700	310/328	USPAT	2002/02/27 11:06
-	114	310/328 and strain\$ same induc\$	USPAT	2002/02/27 10:18
-	17	310/365 and strain\$ same induc\$	USPAT; EPO; JPO; DERWENT	2002/02/27 10:20
-	5	310/349 and strain\$ same induc\$	USPAT; EPO; JPO; DERWENT	2002/02/27 10:20
-	1	("6265811").PN.	USPAT	2002/02/27 11:24
-	2	((("6265811") or ("4517486"))).PN.	USPAT	2002/02/27 11:27
-	1	((("6265811") or ("4517486"))).PN.) and strain\$ near induc\$	USPAT	2002/02/27 11:29
-	2	((("6265811") or ("4517486"))).PN.) and strain\$ same induc\$	USPAT	2002/02/27 11:58
-	1	("6021675").PN.	USPAT	2002/02/27 12:00
-	1	((("6021675").PN.) and "138" same silicon\$	USPAT	2002/02/27 12:00
-	102	310/\$.ccls. and ((strain\$7 induc\$7) near12 silicon\$10)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/05/31 10:26